







ST Bridge Rectifier

STBR series 1200 & 800 V automotive & industrial grade bridge diodes

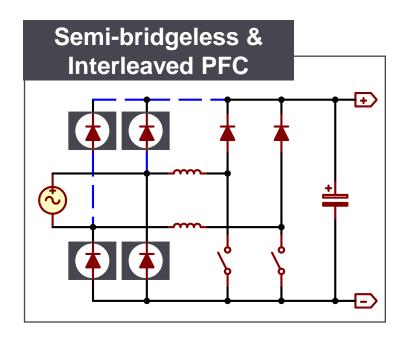
STBR 800 & 1200 V bridge rectifiers

For input bridge, bypass, reverse battery protection, O-ring, etc.

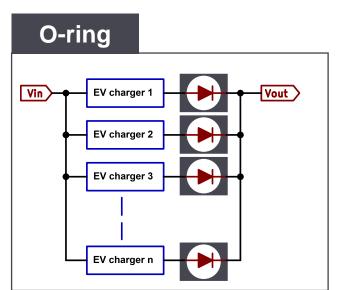


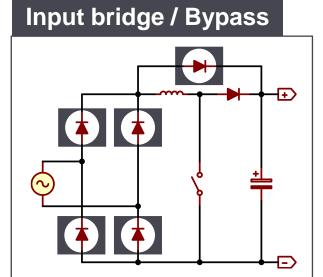


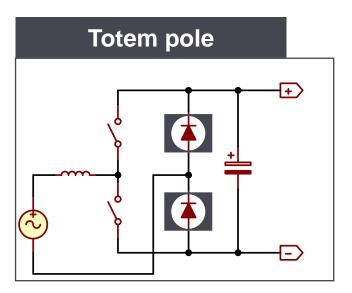
STBR series for low conduction power losses

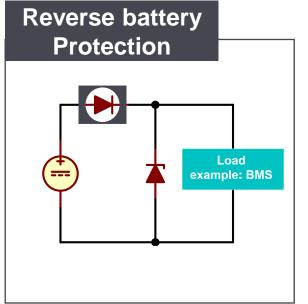








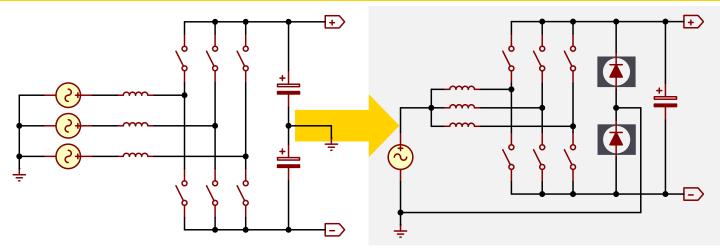






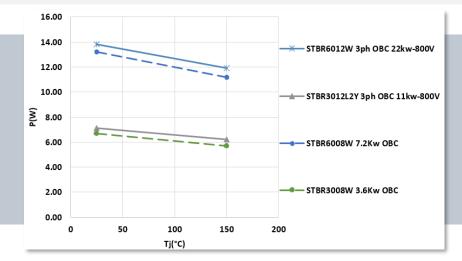
STBR series for low conduction power losses

4 legs allows same power from 3-phase to single-phase



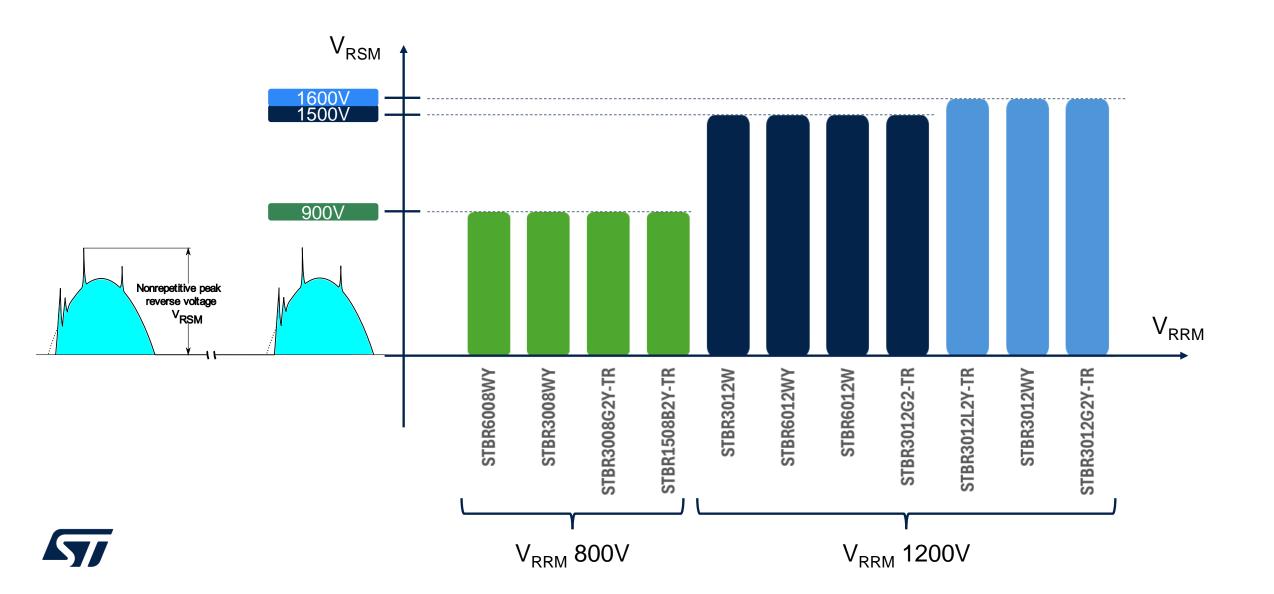
- Easy single phase with four-leg 3-phase PFC
- Less losses than controlled switches
- No gate drivers
- Does not require insulated/floating SMPS
- Save microcontroller ports
- 50 Hz conduction losses reduced
- State-of-the-art and reliable budget solution

Typical conduction losses per diode





Nonrepetitive reverse voltage guaranteed in datasheet

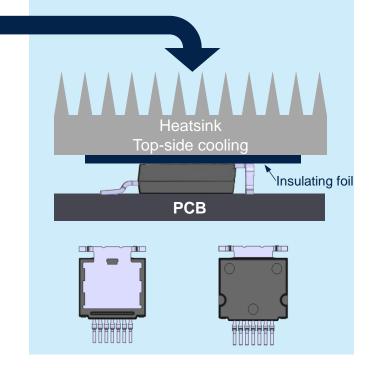


STBR portfolio in mass production

FAV
60A

Commercial Produc	I _{F(AVG)}	V _{RRM} (V)	cp_base quantity		Package name	Package picture
STBR3012L2Y-TR NEW	30	1200	600	600	HU3PAK T.S.C.	
STBR6008WY	60	800	30	600	DO-247	H KI DO DE
STBR3008WY	30	800	30	600		
STBR3012WY	30	1200	30	600		
STBR3012W	30	1200	30	600		
STBR6012WY	60	1200	30	600		
STBR6012W	60	1200	30	600		
STBR3008G2Y-TR	30	800	1000	1000	D ² PAK HV	GI day to
STBR3012G2Y-TR	30	1200	1000	1000		
STBR3012G2-TR	30	1200	1000	1000		
STBR1508B2Y-TR	15	800	2500	2500	DPAK HV	Care.

Top-side cooling allows standard PCBs instead insulated metal substrates



Y = Automotive grade





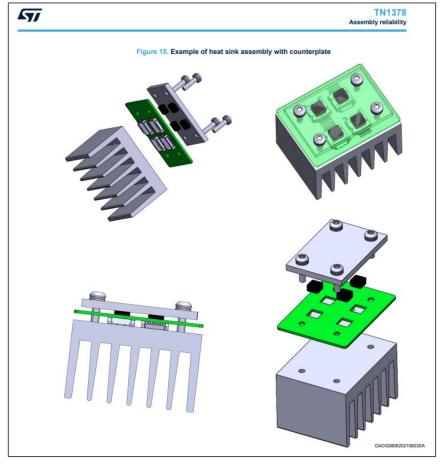


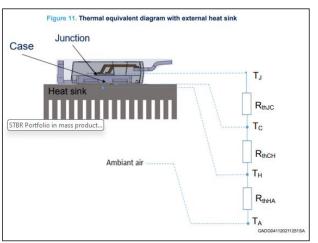
15A

V008

HU3PAK assembly guidelines

Technical note TN1378 provides package mounting and thermal behavior for HU3PAK



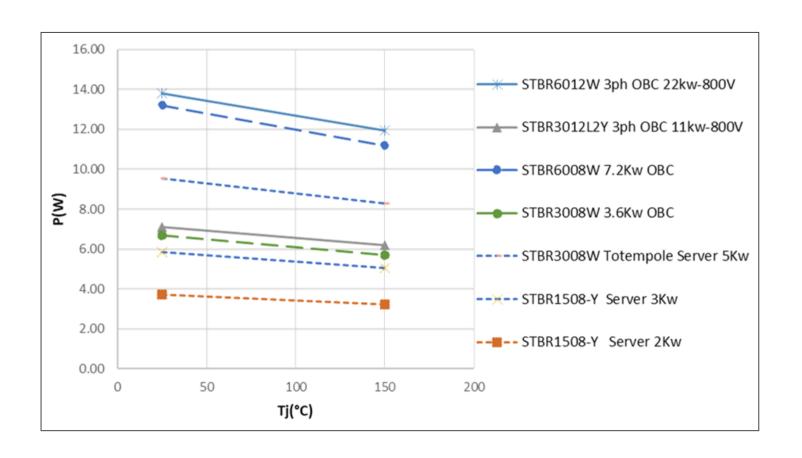






Lower V_F helps reduce conduction losses in low frequency rectification

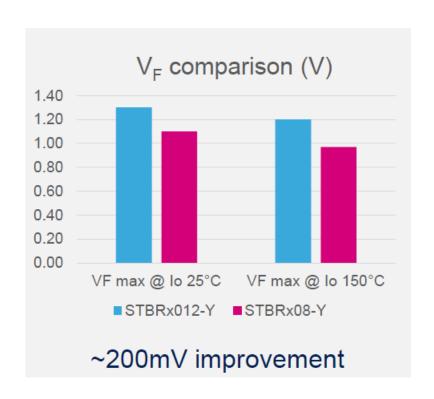
Typical conduction losses per diode



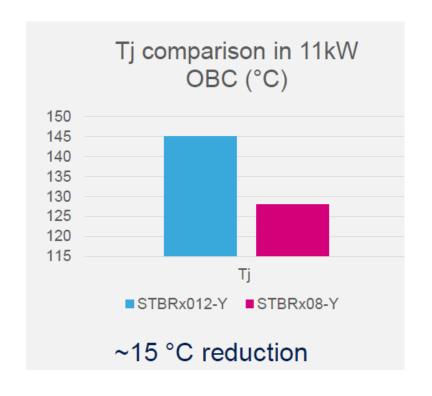


800 V STBR V_F performance

Lower VF reduces diode losses and lowers Tj by 15°C in 11 kW OBCs for improved reliability and flexibility in more compact designs



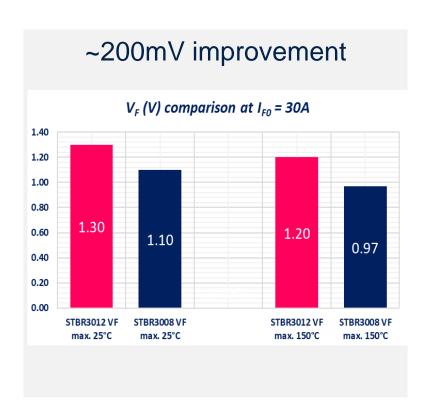


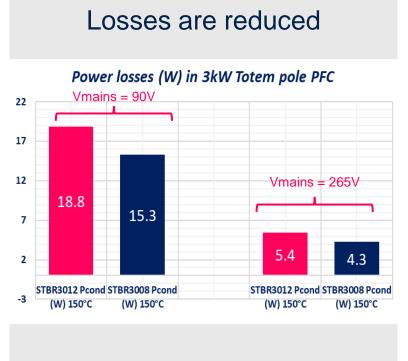


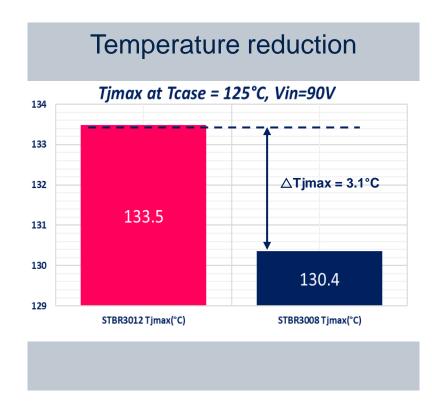


Bridge STBR series V_F performance

Lower VF reduces diode losses and lowers Tj in 3 kW OBCs for improved reliability and flexibility in more compact designs





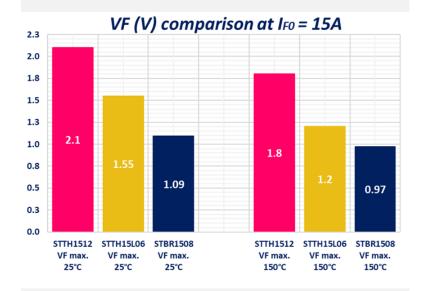




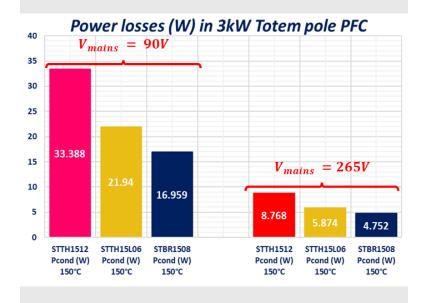
Bridge STBR versus Ultrafast V_F performance

The better VF of STBR1508 reduces diode losses and lowers ~36°C lower Tj than STTH1512D/G and ~29°C than STTH15L06D/G

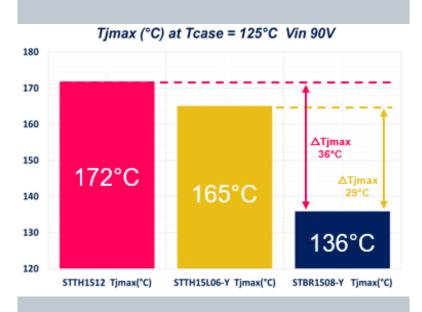
Vf improvement within STBR



Reduced losses in input bridge



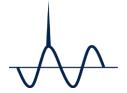
Temp. reduction up to 36°C







Robust and safe automotive-grade STBR



I_{FSM} rated lightning surge capability (IEC61000-4-5)



HV D2PAK, HV DPAK, DO-247, and HU3PAK packages



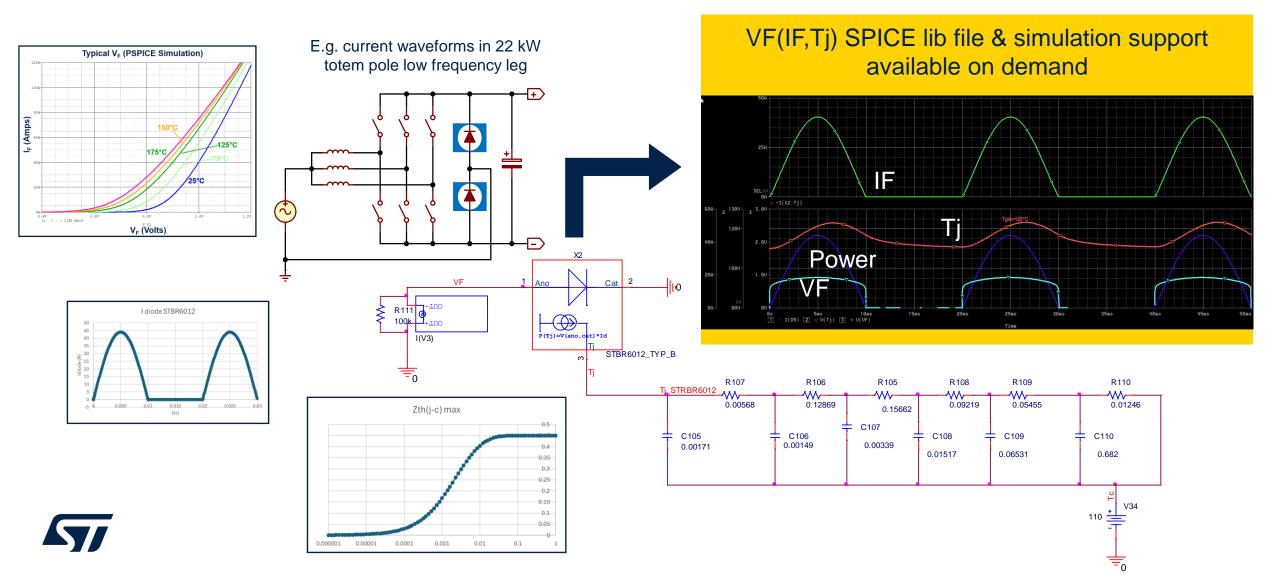
Full V_{RRM} guaranteed (-40 to 175°C) in datasheet



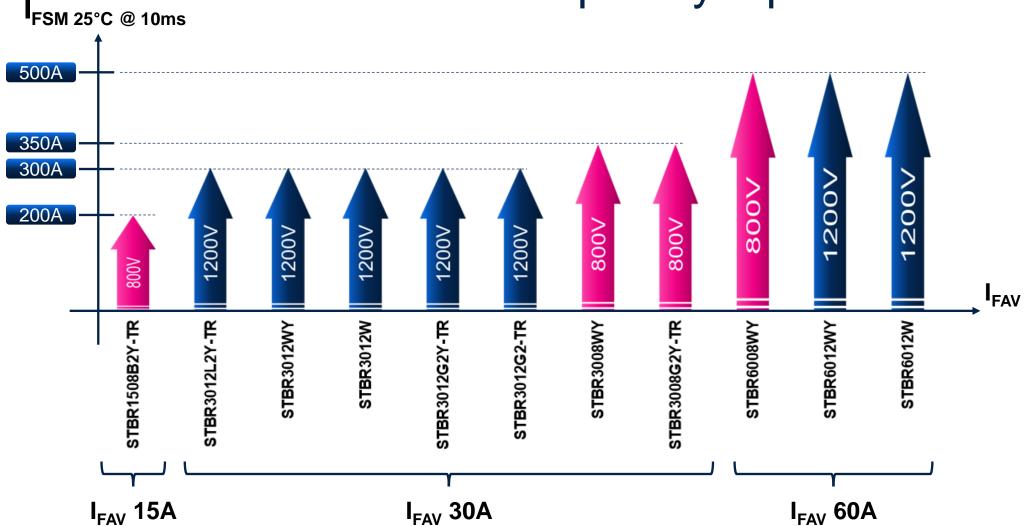
AEC-Q101 qualified – PPAP capable



Eletrothermal simulation

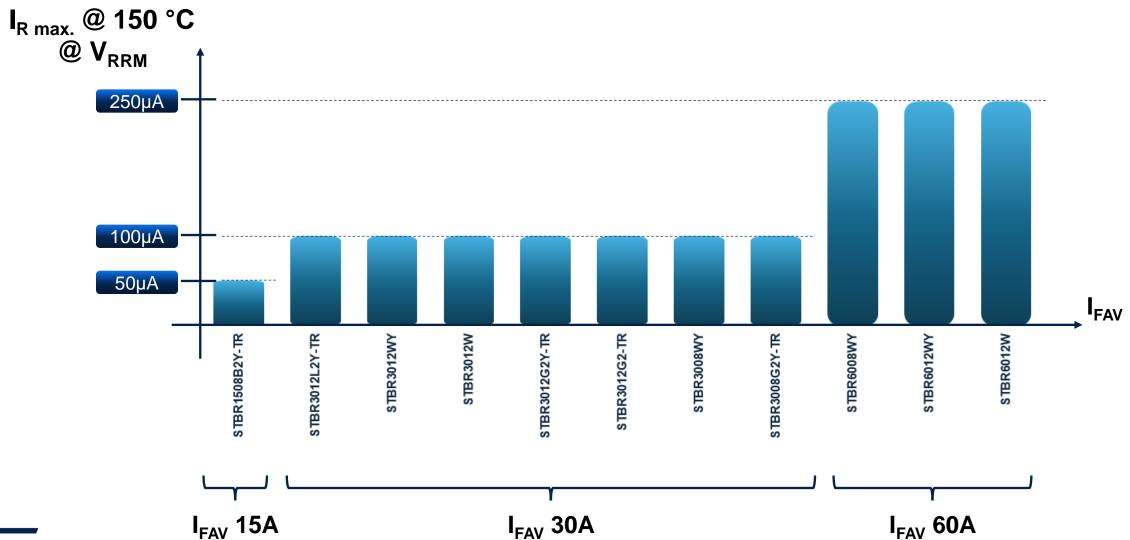


STBR allows high surge capability for low frequency input rectification





STBR has lower (I_R) leakage current versus Ultrafast





Summary of STBR features





Our technology starts with You



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